NSN 5961-01-034-1483

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-034-1483 **Inclosure Material:** Metal **Overall Length:** Between 0.970 inches and 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-59 **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 60.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No **Fiig:**

ı ııg.

A110a0